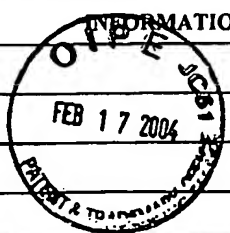


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|  INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Use several sheets if necessary) | | | | Applicant(s): Michael Zhuoying Su | | |
| | | | | Filing Date: November 4, 2003 | | |
| | | | | Group Art Unit: 2811 | | |
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| *EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with your communication to applicant. | | | | | | |